

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	119	("20010015446" "20010020700" "20010023964" "20020017696" "20020066908" "20020167023" "20030020092" "20030102482" "20040021152" "20040029330" "20040061129" "4424525" "4471366" "4727403" "4788156" "4946547" "5053348" "5172197" "5192987" "5200022" "5210051" "5292501" "5296395" "5298445" "5393993" "5523589" "5701019" "5705827" "5885860" "5946547" "6028328" "6046464" "6051849" "6064082" "6177685" "6177688" "6218680" "6255198" "6261929" "6316793" "6376339" "6380108" "6429467" "6448648" "6462355" "6486042" "6489221" "6515316" "6521514" "6545300" "6548333" "6570192" "6582906" "6582986" "6586778" "6586781" "6602763" "6602764" "6608327" "6621148" "6639255" "6686261" "6706114" "RE34861").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 08:35
S2	2	("20010040246").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/02 11:11
S3	8	("20020079508" "20030145784" "5389571" "5990531").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 13:17
S4	16	("20020008241" "20020167023" "20030123829" "20040241970" "4755867" "5686737" "6086673" "6150680").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 13:49
S5	18	(5534462 5700714 5804482 20020119610 6492669 20030017683 20030157776 20030213975 20040004223).pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 13:52
S6	2	"20040029330"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 14:12

S7	12	(20020167023 20020066908 20020017696 20010023964 20010020700 20010015446).pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 14:14
S8	603	"current aperture"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 15:47
S9	145	"current aperture" and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 14:41
S10	30	"hybrid layer" and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 15:48
S11	381	"hybrid layer"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 15:48
S13	1564	257/66.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 08:36
S15	137	S13 and aperture	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 08:50
S16	28247	aperture and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 08:59

S17	30	"hybrid layer" and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 08:59
S18	81	257/218.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 09:28
S19	75	257/219.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 09:28
S20	219	257/221.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 09:49
S21	112	257/224.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 09:57
S25	992	"vertical channel" and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 09:58
S26	210	257/240.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 16:07
S27	77	257/242.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 16:07

S28	165	257/243.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 16:17
S29	1185	257/192.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 16:17
S30	993	257/192.ccls. and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 16:17
S31	262	S30 and vertical	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 16:33
S32	123	S30 and GaN	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 08:14
S33	11	S32 and aperture	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 16:43
S34	10455	GaN and power	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 08:14
S35	319	S34 and HEMT	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 08:53

S36	8656	GaN and vertical	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 08:53
S37	1189	GaN and vertical and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 08:54
S38	960	GaN and vertical and transistor and @ad<"20040520"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 09:44
S39	5336	GaN and "257"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 09:45
S40	1714	S39 and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 10:40
S41	216	257/83.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 10:40
S42	1064	(double adj diffused) and DMOS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 13:40
S43	58	S42 and aperture	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 15:54

S44	78	pendeo-epitaxy	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 16:38
S45	144	pendeo adjepitaxy	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 16:38
S46	99	pendeo adj epitaxy	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 16:38
S47	13	S46 and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/26 16:38
S48	8	("5424227" "5929467" "5990531" "6246076" "6298079" "6316793" "6479843" "6486502").PN. OR ("6878593"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 09:45
S49	22	("4471366" "5192987" "5296395" "5831277" "5929466" "5933705").PN. OR ("6316793"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 09:46
S50	27	("5218216" "5247533" "5523589" "5578839").PN. OR ("5929466").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 09:50
S51	27	("5218216" "5247533" "5523589" "5578839").PN. OR ("5929466").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 09:50
S52	27	("5218216" "5247533" "5523589" "5578839").PN. OR ("5929466").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 09:50
S53	26	("4529455" "5106767" "5180684" "5250448" "5346840").PN. OR ("5424227"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 09:55
S54	3	("5304821" "5488236" "5554862").PN. OR ("6906356"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 10:02

S55	8	("20010015437" "20020052076" "5929467" "6107649" "6140169" "6429467" "6469357" "6593194").PN. OR ("6914273").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 10:05
S56	24	("20010043629" "20020067877" "3919656" "4424525" "4658403" "4683484" "4806997" "4814774" "4827320" "4829272" "4899200" "4949350" "5010374" "5105248" "5202896" "5204871" "5337328" "5386128" "5422501" "5436759" "5652439" "5698900" "6031243" "6647041").PN. OR ("6954473").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 10:09
S57	2	("2001/0043629").URPN.	USPAT	OR	OFF	2005/11/01 10:34
S58	34	("20030017660" "20030075719" "20040178413" "3903592" "4732871" "4737469" "4757028" "4762806" "4803526" "4897710" "4947218" "5229625" "5264713" "5270554" "5289015" "5300795" "5306650" "5396085" "5399883" "5510630" "5686737" "5719409" "5742082" "5869856" "5891769" "5895939" "5900648" "5925895" "5972801" "6107649" "6121633" "6218680" "6316793" "6686616").PN. OR ("6956239").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 14:12
S60	0	Methods of Fabricating Gallium Nitride (GaN) semiconductor Layers by Lateral Growth from Sidewalls into Trenches, and Gallium Nitride Semiconductor Structures Fabricated Thereby	US-PGPUB; USPAT; USOCR	AND	OFF	2005/11/01 14:13
S61	0	Methods Fabricating Gallium Nitride semiconductor Layers by Lateral Growth from Sidewalls into Trenches Gallium Nitride Semiconductor Structures Fabricated Thereby	US-PGPUB; USPAT; USOCR	AND	OFF	2005/11/01 14:13
S62	13	Methods Fabricating Gallium Nitride semiconductor Layers by Lateral Growth	US-PGPUB; USPAT; USOCR	AND	OFF	2005/11/01 14:15
S63	1	"6265289".pn.	US-PGPUB; USPAT; USOCR	AND	OFF	2005/11/02 08:35

S64	49	("4127792" "4522661" "4651407" "4865685" "4876210" "4912064" "4946547" "5122845" "5156995" "5389571" "5397736" "5549747" "5710057" "5760426" "5786606" "5815520" "5877070" "5880485" "5912477" "6051849" "6100104" "6100111" "6156584" "Re34861").PN. OR ("6265289").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 14:17
S65	9	("20010007242" "20030111008" "6153010" "6265289" "6355497" "6413627" "6500257" "6582986" "6836498").PN. OR ("6921673").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 14:18
S66	14	("20030020087" "20030139037" "5249250" "5987048" "6015979" "6153010" "6225650" "6294440" "6377596" "6498048" "6509579" "6586316" "6606335").PN. OR ("6836498"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 14:19
S67	32	("4127792" "4522661" "4651407" "4865685" "4876210" "4912064" "4946547" "5122845" "5156995" "5389571" "5397736" "5549747" "5710057" "5760426" "5786606" "5815520" "5877070" "5880485" "5912477" "5915194" "6051849" "6064078" "6100104" "6100111" "6121121" "6153010" "6156584" "6255198" "6265289" "RE34861").PN. OR ("6376339"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 14:31
S68	25495	epitaxial and transistor	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 14:31
S69	1318	S68 and GAN	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 14:42
S70	1163	S69 and @ad<"20040520"	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 14:33
S71	108	S70 and aperture	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 14:33
S72	666	S70 and vertical	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 14:42

S73	42	S70 and ("vertical channel" or "vertical current" or "vertical transistor")	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/01 14:42
S74	47	S70 and ("vertical channel" or "vertical current" or "vertical transistor")	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/01 14:42
S75	22	PCT/US99/04346	US-PGPUB; USPAT; USOCR	AND	OFF	2005/11/02 08:35
S76	49	("4127792" "4522661" "4651407" "4865685" "4876210" "4912064" "4946547" "5122845" "5156995" "5389571" "5397736" "5549747" "5710057" "5760426" "5786606" "5815520" "5877070" "5880485" "5912477" "6051849" "6100104" "6100111" "6156584" "Re34861").PN. OR ("6265289").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/02 08:52
S77	39	("3977017" "4036672" "4115793" "4124933" "4326209" "4378629" "4499657" "4522661").PN. OR ("4651407").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/02 10:09
S78	1	"6500257".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/02 10:09
S79	10	("4053350" "4522661" "5236544" "5356510" "5494837" "5591666").PN. OR ("6500257").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/02 10:09
S80	475	HEMT and GAN	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/02 11:22
S81	582	HEMT and GAN	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/02 11:12
S82	192	HEMT and GAN and vertical	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/02 11:24

S83	165	HEMT and GAN and vertical and (epitaxy or epitaxial or epi)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/02 11:25
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